

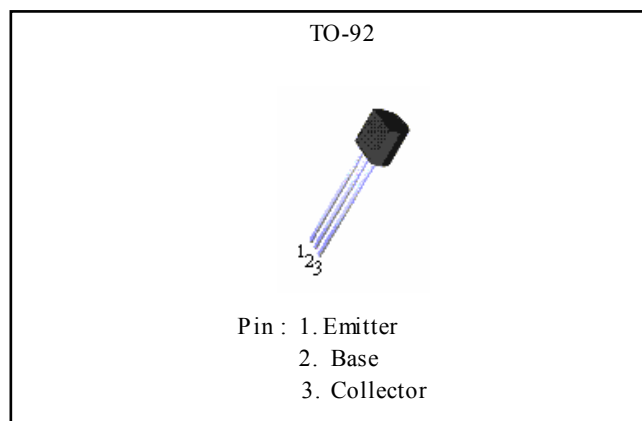
**PNP Epitaxial Silicon Transistors**

**AMPLIFIER TRANSISTOR**

- Collector-Base Voltage:  $V_{CE0}=120V$
- Collector Dissipation  $P_c=0.625W(T_c=25^{\circ}C)$

**ABSOLUTE MAXIMUM RATINGS** ( $T_a = 25^{\circ}C$ )

Characteristic	Symbol	Rating	Unit
Collector-base Voltage	$V_{CBO}$	130	V
Collector-Emitter Voltage	$V_{CEO}$	120	V
Emitter-base Voltage	$V_{EBO}$	5	V
Collector Current (DC)	$I_C$	0.6	A
* Collector Dissipation	$P_C$	0.625	W
Junction Temperature	$T_J$	150	$^{\circ}C$
Storage Temperature	$T_{stg}$	-55~150	$^{\circ}C$



**ORDERING INFORMATION**

Device	Operating Temperature	Package
PJ2N5401CT	-20 $^{\circ}C$ ~ +85 $^{\circ}C$	TO-92

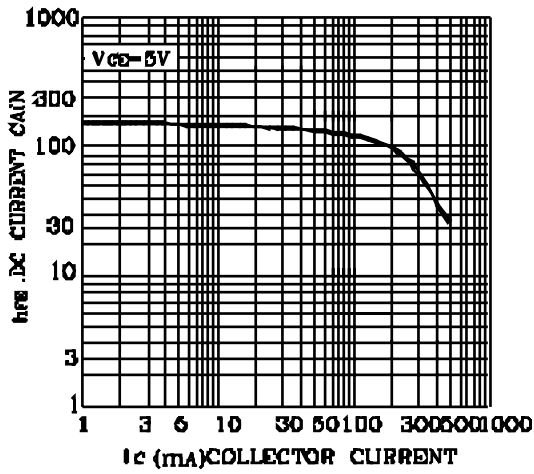
**ELECTRICAL CHARACTERISTICS** ( $T_a=25^{\circ}C$ )

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	$BV_{CBO}$	$I_c=100 \mu A, I_E=0$	130			V
Collector- Emitter Breakdown Voltage	$BV_{CEO}$	$I_c=1mA, I_B=0$	120			V
Emitter-Base Breakdown Voltage	$BV_{EBO}$	$I_E=10 \mu A, I_C=0$	5			V
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=200V, I_E=0$			100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=3V, I_C=0$			50	nA
DC Current Gain	$H_{EF1}$	$V_{CE}=10V, I_C=1 mA$	30			
		$V_{CE}=10V, I_C=10mA$	40			
		$V_{CE}=10V, I_C=50mA$	40			
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_c=10 mA, I_B=1 mA$			0.2	V
		$I_c=50 mA, I_B=5 mA$			0.5	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_c=10 mA, I_B=1 mA$			1	V
		$I_c=50 mA, I_B=5 mA$			1	V
Output Capacitance	$C_{ob}$	$V_{CB}=20V, I_E=0, f=1MHz$			6	PF
Current Gain-Bandwidth product	$f_T$	$V_{CE}=5V, I_c=10mA$	100		400	MHz
Noise Figure	NF	$V_{CE}=5V, I_c=0.2 mA$ $R_S=1K, f=10KHz$			8	dB

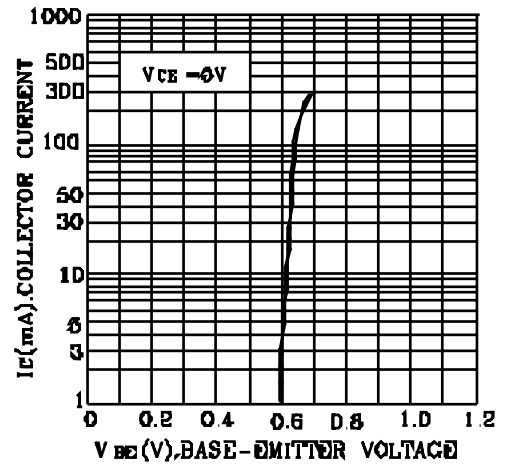
- Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2\%$ .

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DC CURRENT GAIN



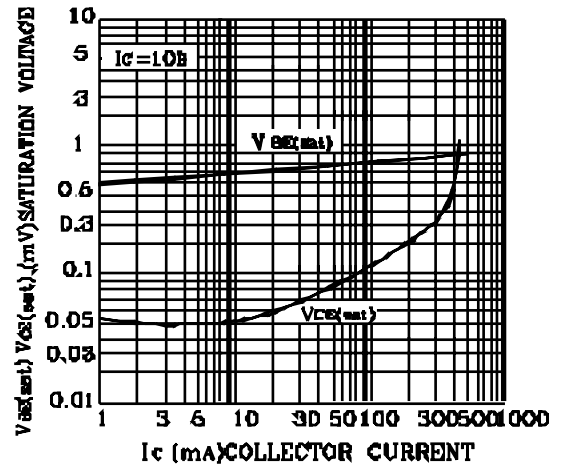
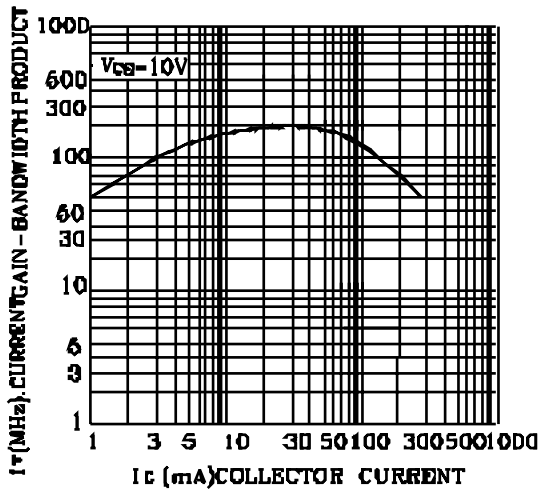
BASE-EMITTER ON VOLTAGE



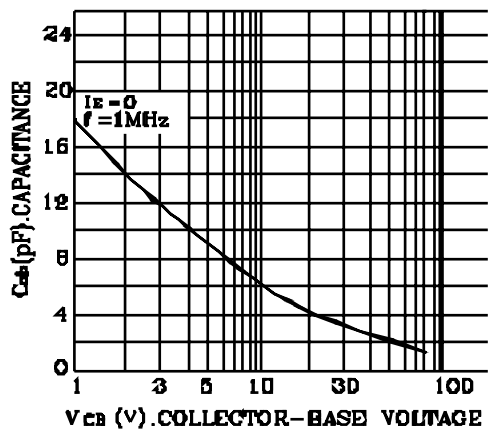
BASE-EMITTER SATURATION VOLTAGE

COLLECTOR-EMITTER SATURATION VOLTAGE

CURRENT GAIN-BANDWIDTH PRODUCT



OUTPUT CAPACITANCE



TO-92 Unit:mm

